TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (π -MOSVI)

2SK3903

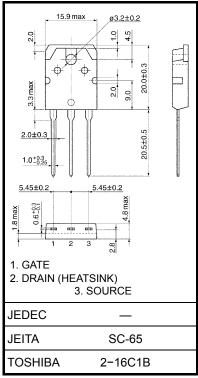
Switching Regulator Applications

Unit: mm

- Low drain-source ON resistance: $R_{DS (ON)} = 0.32 \Omega (typ.)$
- High forward transfer admittance: $|Y_{fS}| = 7.5 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 100 \mu A (max) (V_{DS} = 600 V)$
- Enhancement model: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristic | | | Symbol | Rating | Unit | |
|--|----------|---------|------------------|------------|------|--|
| Drain-source voltage | | | V_{DSS} | 600 | V | |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | | V_{DGR} | 600 | ٧ | |
| Gate-source voltage | | | V_{GSS} | ±30 | V | |
| Drain current | DC (N | Note 1) | I _D | 14 | Α | |
| | Pulse (N | Note 1) | I _{DP} | 56 | " | |
| Drain power dissipation (Tc = 25°C) | | | P _D | 150 | W | |
| Single pulse avalanche energy (Note 2) | | | E _{AS} | 806 | mJ | |
| Avalanche current | | | I _{AR} | 14 | Α | |
| Repetitive avalanche energy (Note 3) | | | E _{AR} | 15 | mJ | |
| Channel temperature | | | T _{ch} | 150 | °C | |
| Storage temperature range | | | T _{stg} | -55 to 150 | °C | |



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristic | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W |

10

Note 1: Ensure that the channel temperature does not exceed 150°C during use of the device.

Note 2: $V_{DD} = 90 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$, L = 7.2 mH, $R_G = 25 \Omega$, $I_{AR} = 14 \text{ A}$

Note 3: Repetitive rating: pulse width limited by max junction temperature

This transistor is an electrostatic-sensitive device. Handle with care.

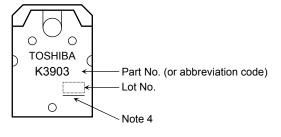
Electrical Characteristics (Ta = 25°C)

| Char | acteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|---------------|----------------------|--|-----|------|------|------|
| Gate leakage current | | I _{GSS} | $V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±10 | μА |
| Gate-source breakdown voltage | | V (BR) GSS | $I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$ | ±30 | _ | _ | V |
| Drain cut-off current | | I _{DSS} | V _{DS} = 600 V, V _{GS} = 0 V | _ | _ | 100 | μА |
| Drain-source breakdown voltage | | V (BR) DSS | $I_D = 10$ mA, $V_{GS} = 0$ V | 600 | _ | _ | V |
| Gate threshold voltage | | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source on resistance | | R _{DS} (ON) | V _{GS} = 10 V, I _D = 7 A | _ | 0.32 | 0.44 | Ω |
| Forward transfer admittance | | Yfs | V _{DS} = 10 V, I _D = 7 A | 2.1 | 7.5 | _ | S |
| Input capacitance | | C _{iss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | _ | 3100 | _ | pF |
| Reverse transfer capacitance | | C _{rss} | | _ | 20 | _ | |
| Output capacitance | | Coss | | _ | 270 | _ | |
| Switching time | Rise time | t _r | $\begin{array}{c c} \text{10 V} & \text{I}_D = 7 \text{ A} \\ \text{0 V} & \text{OUT} \\ \hline \\ \text{0 V} & \text{RL} = 29 \ \Omega \\ \hline \\ \text{VDD} \approx 200 \ \text{V} \\ \\ \text{Duty} \leq 1\%, \ t_\text{W} = 10 \ \mu\text{s} \\ \end{array}$ | _ | 70 | _ | ns |
| | Turn-on time | t _{on} | | _ | 130 | _ | |
| | Fall time | t _f | | | 70 | | |
| | Turn-off time | t _{off} | | _ | 280 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | $V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 14 \text{ A}$ | | 62 | _ | nC |
| Gate-source charge | | Q _{gs} | | _ | 40 | | |
| Gate-drain ("Miller") charge | | Q _{gd} | | _ | 22 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 14 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 56 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 14 A, V _{GS} = 0 V | _ | _ | -1.7 | ٧ |
| Reverse recovery time | t _{rr} | $I_{DR} = 14 \text{ A}, V_{GS} = 0 \text{ V},$ | _ | 1300 | _ | ns |
| Reverse recovery charge | Q _{rr} | dI _{DR} /dt = 100 A/μs | _ | 18 | | μС |

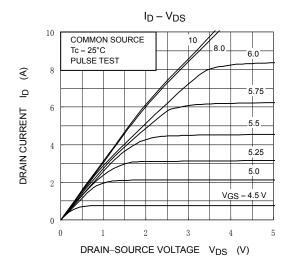
Marking

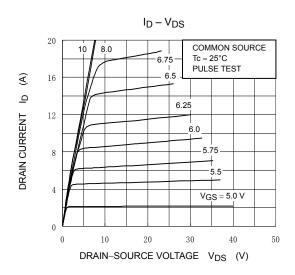


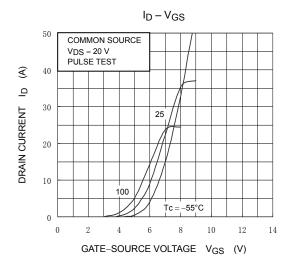
Note 4: A line under a Lot No. identifies the indication of product Labels.

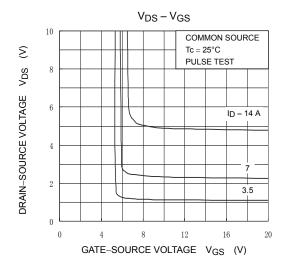
[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

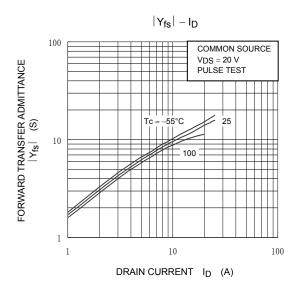
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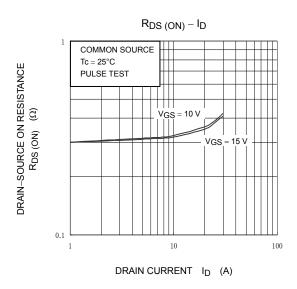




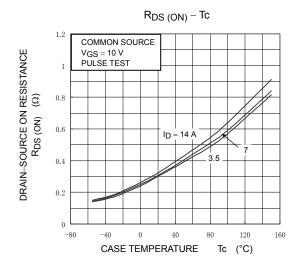


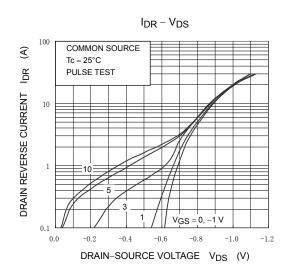


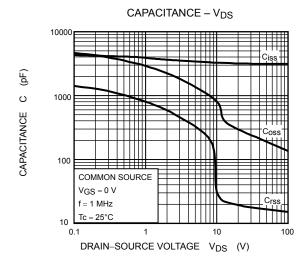


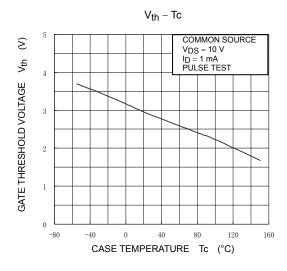


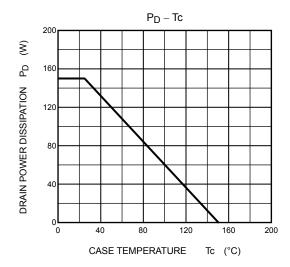
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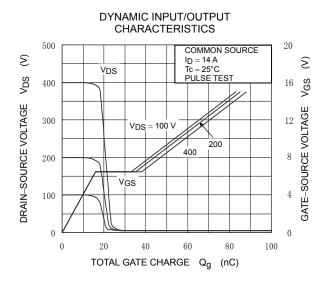


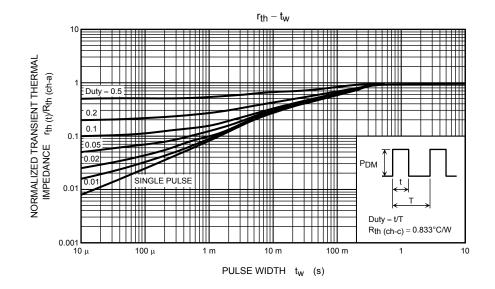


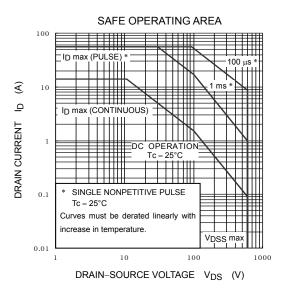


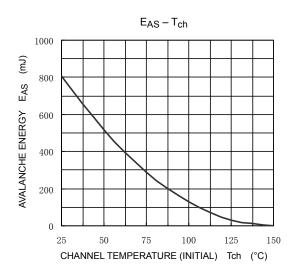


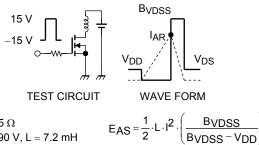












$$R_G = 25 \Omega$$

$$V_{DD} = 90 \text{ V, L} = 7.2 \text{ mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS} - V_{DD} \right)$$

2009-09-29 5

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